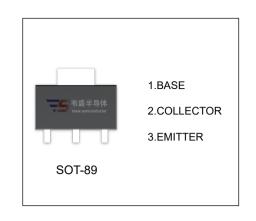


## PXT2907A TRANSISTOR (PNP)

## **FEATURES**

- Switching and Linear Amplification
- High Current and Low Voltage
- Complement to PXT2222A



## MAXIMUM RATINGS (T<sub>a</sub>=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	-60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-60	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
Ic	Collector Current	-600	mA
Pc	Collector Power Dissipation	500	mW
R <sub>θJA</sub>	Thermal Resistance From Junction To Ambient	250	°C/W
T <sub>J</sub> ,T <sub>stg</sub>	Operation Junction and Storage Temperature Range	-55~+150	℃

ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless otherwise specified)

Parameter Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =-1mA,I <sub>E</sub> =0	-60	7.		V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =-10mA,I <sub>B</sub> =0	-60			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =-1mA,I <sub>C</sub> =0	-5			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =-50V,I <sub>E</sub> =0			-0.01	μΑ
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =-5V,I <sub>C</sub> =0			-0.01	μΑ
	h <sub>FE</sub>	V <sub>CE</sub> =-10V, I <sub>C</sub> =-0.1mA	75			
		V <sub>CE</sub> =-10V, I <sub>C</sub> =-1mA	100			
DC current gain		V <sub>CE</sub> =-10V, I <sub>C</sub> =-10mA	100			
		V <sub>CE</sub> =-10V, I <sub>C</sub> =-150mA	100		300	
		V <sub>CE</sub> =-10V, I <sub>C</sub> =-500mA	50			
Callegton omitten actuaction valtere	V <sub>CE(sat)</sub>	I <sub>C</sub> =-500mA,I <sub>B</sub> =-50mA			-1.6	V
Collector-emitter saturation voltage		I <sub>C</sub> =-150mA,I <sub>B</sub> =-15mA			-0.4	V
Dog a maitte was trumption welfare	V <sub>BE(sat)</sub>	I <sub>C</sub> =-500mA,I <sub>B</sub> =-50mA			-2.6	V
Base-emitter saturation voltage		I <sub>C</sub> =-150mA,I <sub>B</sub> =-15mA			-1.3	V
Delay time	t <sub>d</sub>	- V <sub>CC</sub> =-30V, I <sub>C</sub> =-150mA, - I <sub>B1</sub> =- I <sub>B2</sub> =-15mA			12	ns
Rise time	t <sub>r</sub>				30	ns
Storage time	ts				300	ns
Fall time	t <sub>f</sub>				65	ns
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =-10V,I <sub>C</sub> =-20mA, f=100MHz	200			MHz



